

IZUMI  
Serial No. 10/520,928  
Response to Office Action dated November 28, 2005

**AMENDMENTS TO THE SPECIFICATION:**

Please replace the paragraph beginning on page 27, line 13 with the following amended paragraph:

As While, as shown in Fig. 1(a), in the pixel capacitor section 7, the aforementioned gate insulating film 24 is used as a dielectric layer. The pixel capacitor section 7 includes the gate insulating film 24, provided between the storage capacitor electrode 16 formed in the same layer as the gate electrode 14 and an electrode extended from the drain electrode 15, as the dielectric layer. In the present embodiment, the pixel capacitor section 7 is formed in parallel with a forming process of the TFT section 6.

Please replace the paragraph beginning on page 32, line 18 with the following amended paragraph:

The While the electric charge of the pixel capacitor section 7 is maintained in an area which does not receive the reflected light, for example.

Please replace the Abstract with the replacement Abstract on a separate sheet in the Appendix.

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**AMENDMENT TO THE TITLE:**

Please change the title of the application to  
PHOTOELECTRIC CONVERSION DEVICE AND IMAGE SCANNING APPARATUS